ART700FH; ART700FHS; ART700FHG Power LDMOS transistor

AMPLEON Product data sheet

Product profile 1.

1.1 General description

Based on Advanced Rugged Technology (ART), this 700 W LDMOS RF power transistor has been designed to cover a wide range of applications for ISM, broadcast and non cellular communications. The unmatched transistor has a frequency range of 1 MHz to 450 MHz.

Table 1. **Application information**

| Test signal | f | V _{DS} | PL | G _p | η _D |
|------------------|-------|-----------------|-----|----------------|----------------|
| | (MHz) | (V) | (W) | (dB) | (%) |
| CW pulsed [1][2] | 108 | 50 | 700 | 27 | 81.5 |
| CW pulsed [1][2] | 108 | 55 | 800 | 28.5 | 80 |
| CW [1] | 108 | 55 | 800 | 27.5 | 79.5 |

[1] Production circuit.

[2] $t_p = 100 \ \mu s; \ \delta = 10 \ \%.$

1.2 Features and benefits

- High breakdown voltage enables class E operation at V_{DS} = 48 V
- Suitable for V_{DS} = 50 and 55 V
- Qualified up to a maximum of V_{DS} = 55 V
- Characterized from 30 V to 55 V to support a wide range of applications
- Integrated dual sided ESD protection enables class C operation and complete switch off of the transistor
- Excellent ruggedness with no device degradation
- High efficiency
- Excellent thermal stability
- Designed for broadband operation
- For RoHS compliance see the product details on the Ampleon website

1.3 Applications

- Industrial, scientific and medical applications
 - Plasma generators
 - MRI systems
 - CO₂ lasers
 - Particle accelerators
- Broadcast
 - FM radio
 - VHF TV
- Communications
 - Non cellular communications
 - UHF radar

2. Pinning information

| Pin | Description | Simplified outline | Graphic symbol |
|---------|---------------|--------------------|----------------|
| ART700F | H (SOT1214A) | | |
| 1 | drain1 | | |
| 2 | drain2 | | |
| 3 | gate1 | | |
| 4 | gate2 | 3 4 | 3 5 |
| 5 | source | [1] | |
| | | | |
| | | | sym117 |
| ART700F | HS (SOT1214B) | | |
| 1 | drain1 | | |
| 2 | drain2 | | |
| 3 | gate1 | | |
| 4 | gate2 | 3 4 5 | |
| 5 | source | [1] | |
| | | | ۲ |
| | | | 2 sym117 |
| ART700F | HG (SOT1214C) | | |
| 1 | drain1 | | |
| 2 | drain2 | | |
| 3 | gate1 | | |
| 4 | gate2 | | |
| 5 | source | <u>[1]</u> | |
| | | | ۲ <u>۲</u> |
| | | | 2 sym117 |

[1] Connected to flange.

ART2K0FE_2K0FES_2K0FEG

3. Ordering information

| Package name | Orderable part number | 12NC | Packing description | Min. orderable quantity (pieces) |
|--------------|-----------------------|----------------|-------------------------------------|-------------------------------------|
| SOT1214A | ART700FHU | 9349 604 89112 | Tray; 20-fold; non-dry pack | 60 |
| SOT1214B | ART700FHSU | 9349 605 47112 | Tray; 20-fold; non-dry pack | 60 |
| SOT1214C | ART700FHGJ | 9349 605 48118 | TR13; 100-fold; 44 mm; non-dry pack | 100 |

4. Limiting values

Table 4. Limiting values

In accordance with the Absolute Maximum Rating System (IEC 60134).

| Symbol | Parameter | Conditions | Min | Max | Unit |
|------------------|----------------------|------------|-----|------|------|
| V _{DS} | drain-source voltage | | - | 177 | V |
| V _{GS} | gate-source voltage | | -9 | +13 | V |
| T _{stg} | storage temperature | | -65 | +150 | °C |
| Tj | junction temperature | <u>[1]</u> | - | 225 | °C |

[1] Continuous use at maximum temperature will affect the reliability, for details refer to the online MTF calculator.

5. Thermal characteristics

Table 5. Thermal characteristics

| Symbol | Parameter | Conditions | Тур | Unit |
|----------------------|--|---|-------|------|
| R _{th(j-c)} | thermal resistance from junction to case | $T_j = 120 \ ^{\circ}C$ [1][2] | 0.175 | K/W |
| 11(10) | - | $T_j = 120 \ ^{\circ}C; t_p = 100 \ \mu s;$ [3] $\delta = 10 \ \%$ | 0.052 | K/W |

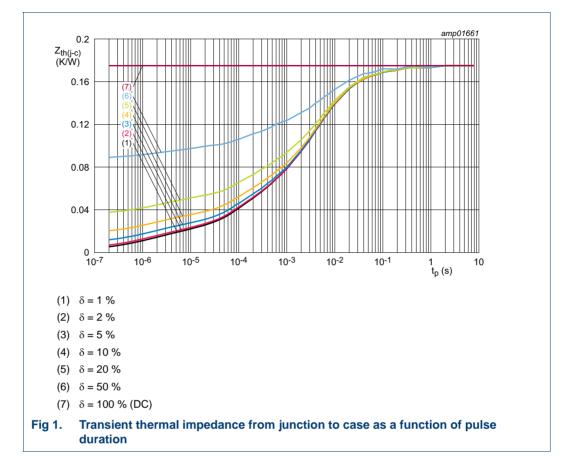
[1] T_j is the junction temperature.

[2] R_{th(j-c)} is measured under RF conditions.

[3] See Figure 1.

ART700FH(S)(G)

Power LDMOS transistor



6. Characteristics

Table 6. DC characteristics

 $T_j = 25 \ ^{\circ}C$; per section unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|----------------------|----------------------------------|---|-----|-------|-----|------|
| V _{(BR)DSS} | drain-source breakdown voltage | V _{GS} = 0 V; I _D = 2.8 mA | 177 | 191 | - | V |
| V _{GS(th)} | gate-source threshold voltage | $V_{DS} = 20 \text{ V}; \text{ I}_{D} = 275 \text{ mA}$ | 1.5 | 2.1 | 2.5 | V |
| I _{DSS} | drain leakage current | $V_{GS} = 0 V; V_{DS} = 50 V$ | - | - | 1.4 | μA |
| I _{DSX} | drain cut-off current | $V_{GS} = V_{GS(th)} + 3.75 V;$ $V_{DS} = 20 V$ | - | 40 | - | A |
| I _{GSS} | gate leakage current | V _{GS} = 13 V; V _{DS} = 0 V | - | - | 140 | nA |
| R _{DS(on)} | drain-source on-state resistance | $V_{GS} = V_{GS(th)} + 3.75 V;$ I _D = 9.625 A | - | 0.171 | - | Ω |

Power LDMOS transistor

| Table 7. | AC | characteristics |
|----------|----|------------------|
| | AC | character istics |

 $T_i = 25$ °C; per section unless otherwise specified.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|----------------------|----------------------------------|-----|------|-----|------|
| C _{rs} | feedback capacitance | V _{GS} = 0 V; f = 1 MHz | | | | |
| | | V _{DS} = 50 V | - | 1.04 | - | pF |
| | | V _{DS} = 55 V | - | 1.00 | - | pF |
| C _{iss} | input capacitance | V _{GS} = 0 V; f = 1 MHz | | | | |
| | | V _{DS} = 50 V | - | 312 | - | pF |
| | | V _{DS} = 55 V | - | 312 | - | pF |
| C _{oss} | output capacitance | V _{GS} = 0 V; f = 1 MHz | | | | |
| | | V _{DS} = 50 V | - | 97 | - | pF |
| | | V _{DS} = 55 V | - | 93 | - | pF |

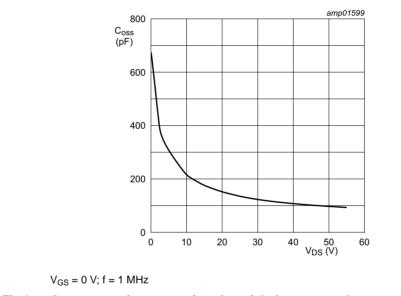


Fig 2. Output capacitance as a function of drain-source voltage; typical values per section

Table 8. RF characteristics

Test signal: pulsed RF; $t_p = 100 \ \mu$ s; $\delta = 10 \ \%$; $f = 108 \ MHz$; RF performance at $V_{DS} = 55 \ V$; $I_{Dq} = 25 \ mA$ per section; $T_{case} = 25 \ ^{\circ}C$; unless otherwise specified; in a class-AB production test circuit.

| Symbol | Parameter | Conditions | Min | Тур | Max | Unit |
|------------------|-------------------|------------------------|------|-------|-----|------|
| G _p | power gain | P _L = 800 W | 26.8 | 28.6 | - | dB |
| RL _{in} | input return loss | P _L = 800 W | - | -32.7 | - | dB |
| η _D | drain efficiency | P _L = 800 W | 73.0 | 77.6 | - | % |

7. Test information

7.1 Ruggedness in class-AB operation

The ART700FH, ART700FHS and ART700FHG are capable of withstanding a load mismatch corresponding to VSWR ≥ 65 : 1 through all phases under the following conditions: P_L = 700 W pulsed at V_{DS} = 50 V and P_L = 800 W pulsed at V_{DS} = 55 V; I_{Dg} = 50 mA per section; t_p = 100 µs; δ = 10 %; f = 108 MHz.

7.2 Impedance information

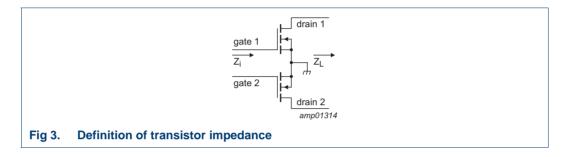


Table 9.Typical push-pull impedanceSimulated Z_i and Z_L device impedance.

| f | Z _i | ZL | PL |
|------------------------|----------------|--------------|-----|
| (MHz) | (Ω) | (Ω) | (W) |
| V _{DS} = 50 V | | | |
| 108 | 4.75 – j17.00 | 6.60 + j1.10 | 700 |
| V _{DS} = 55 V | | | |
| 108 | 4.75 – j17.00 | 6.95 + j1.30 | 800 |

7.3 Test circuit

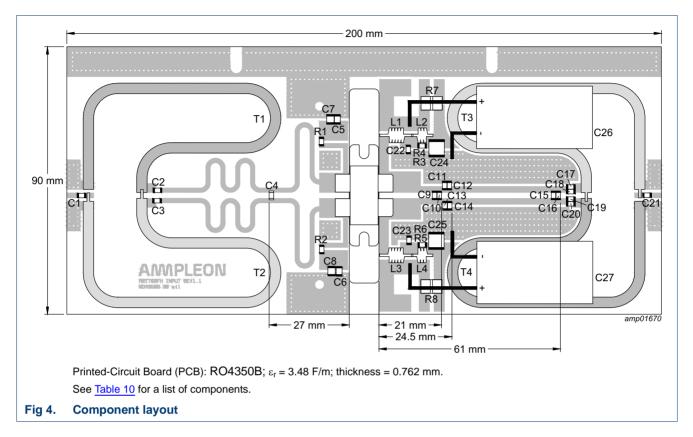


Table 10. List of components

For test circuit see Figure 4.

| Component | Description | Value | Remarks |
|--------------------|-----------------------------------|------------------|----------------------------|
| C1 | multilayer ceramic chip capacitor | 510 pF [1] | |
| C2, C3 | multilayer ceramic chip capacitor | 62 pF [1] | |
| C4 | multilayer ceramic chip capacitor | 160 pF [1] | |
| C5, C6, C22, C23 | multilayer ceramic chip capacitor | 820 pF [1] | |
| C7, C8 | multilayer ceramic chip capacitor | 4.7 μF, 50 V | Murata: GRM32ER71H475KA88L |
| C9, C10 | multilayer ceramic chip capacitor | 36 pF [1] | |
| C11, C12, C13, C14 | multilayer ceramic chip capacitor | 56 pF [1] | |
| C15 | multilayer ceramic chip capacitor | 43 pF [1] | |
| C16 | multilayer ceramic chip capacitor | 47 pF [1] | |
| C17, C18, C19, C20 | multilayer ceramic chip capacitor | 62 pF [1] | |
| C21 | multilayer ceramic chip capacitor | 220 pF [1] | |
| C24, C25 | multilayer ceramic chip capacitor | 4.7 μF, 100 V | TDK: C5750X7R2A475KT/A |
| C26, C27 | electrolytic capacitor | 1500 μF, 80 V | radial leaded |
| L1, L3 | 1 mm copper wire | 5 turn, D = 4 mm | |
| L2, L4 | 1 mm copper wire | 3 turn, D = 4 mm | |
| R1, R2 | chip resistor | 4.7 kΩ | SMD 1206 |

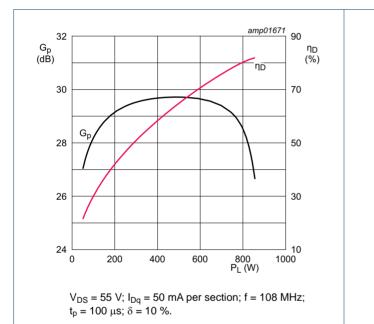
Table 10. List of components ...continued

| For test circuit see | Figure 4. |
|----------------------|-----------|
|----------------------|-----------|

| Component | Description | Value | Remarks |
|----------------|--------------------|--------------|------------------|
| R3, R4, R5, R6 | chip resistor | 20 kΩ | SMD 1206 |
| R7, R8 | chip resistor | 0.01 Ω | Vishay: WSHP2818 |
| T1, T2, T3, T4 | hand formable coax | 50 Ω, 160 mm | SUCOFORM 141 |

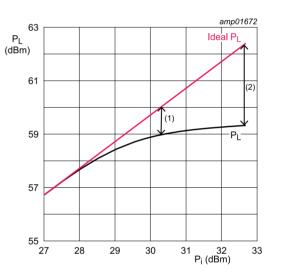
[1] AVX type 800B or capacitor of same quality.

7.4 Graphical data



7.4.1 1-Tone CW pulsed

Fig 5. Power gain and drain efficiency as function of output power; typical values

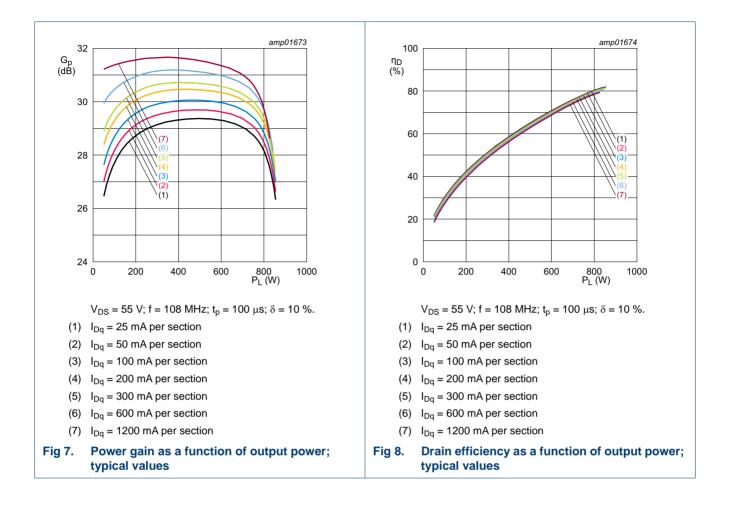


 V_{DS} = 55 V; I_{Dq} = 50 mA per section; f = 108 MHz; t_p = 100 $\mu s;$ δ = 10 %.

- (1) P_{L(1dB)} = 58.95 dBm (785 W)
- (2) P_{L(3dB)} = 59.32 dBm (855 W)
- Fig 6. Output power as a function of input power; typical values

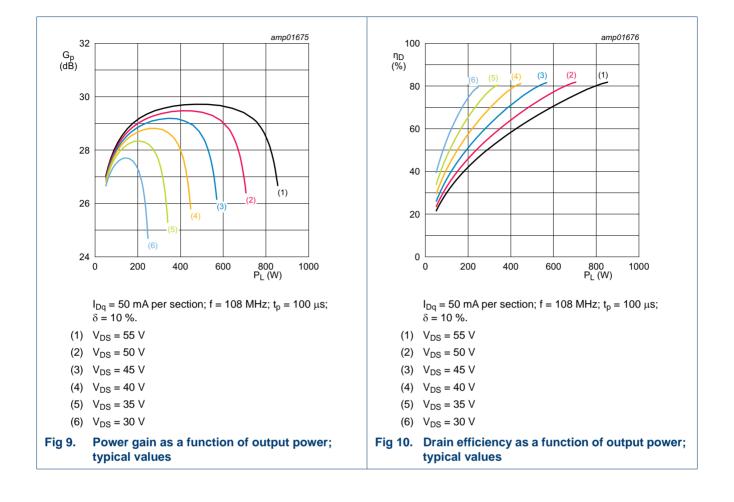
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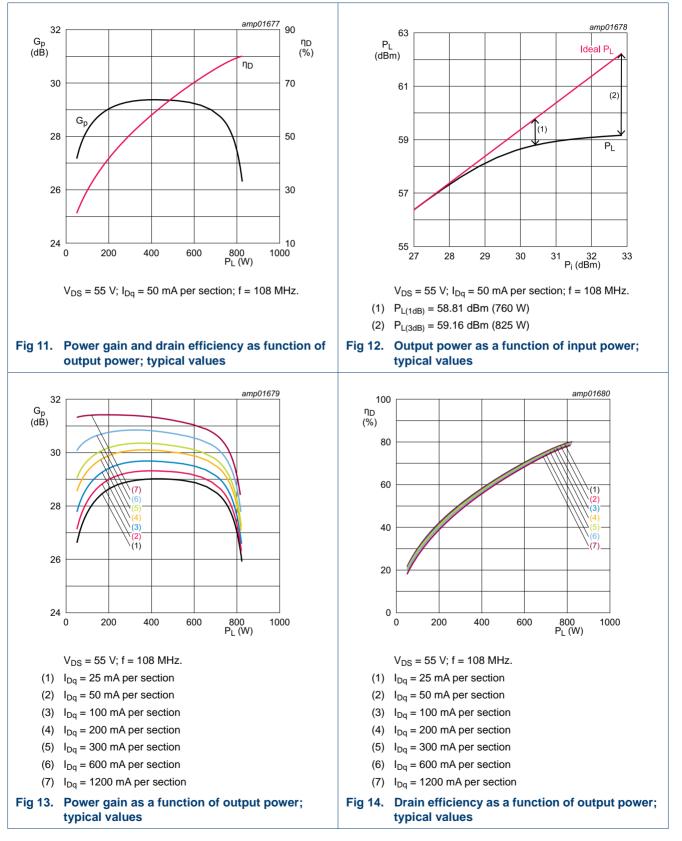


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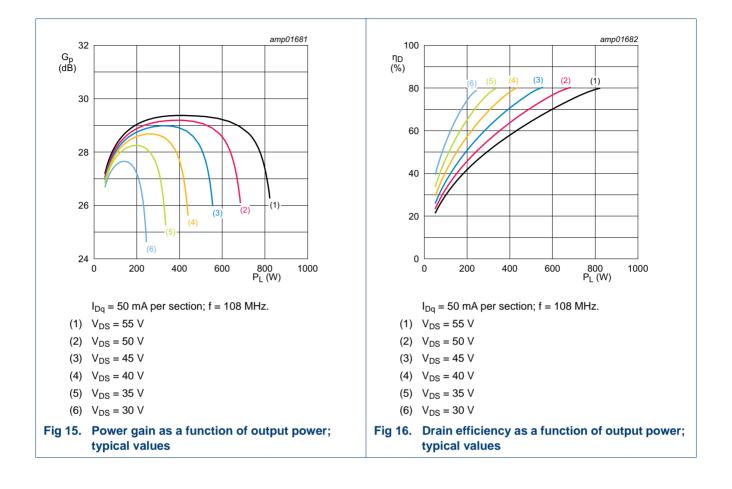


7.4.2 1-Tone CW



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ART700FH(S)(G) Power LDMOS transistor

8. Package outline

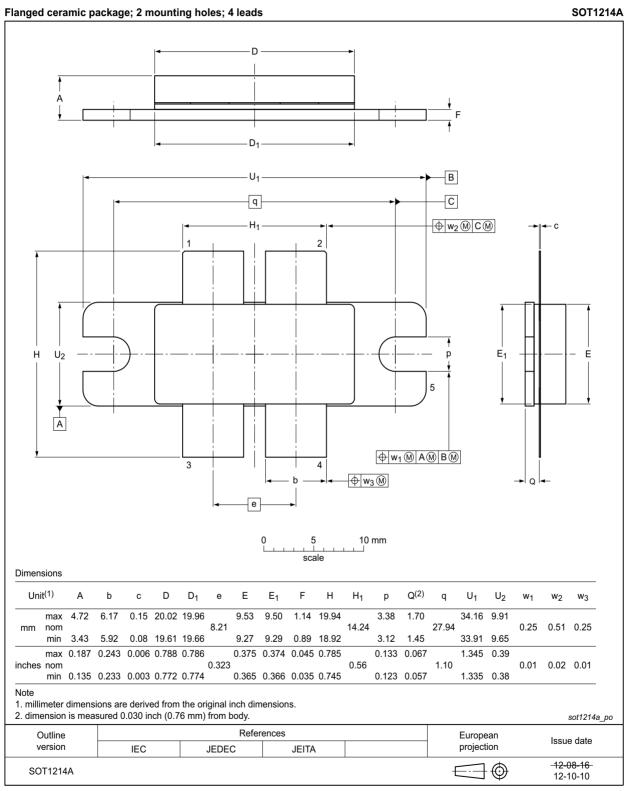


Fig 17. Package outline SOT1214A

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ART700FH(S)(G) Power LDMOS transistor

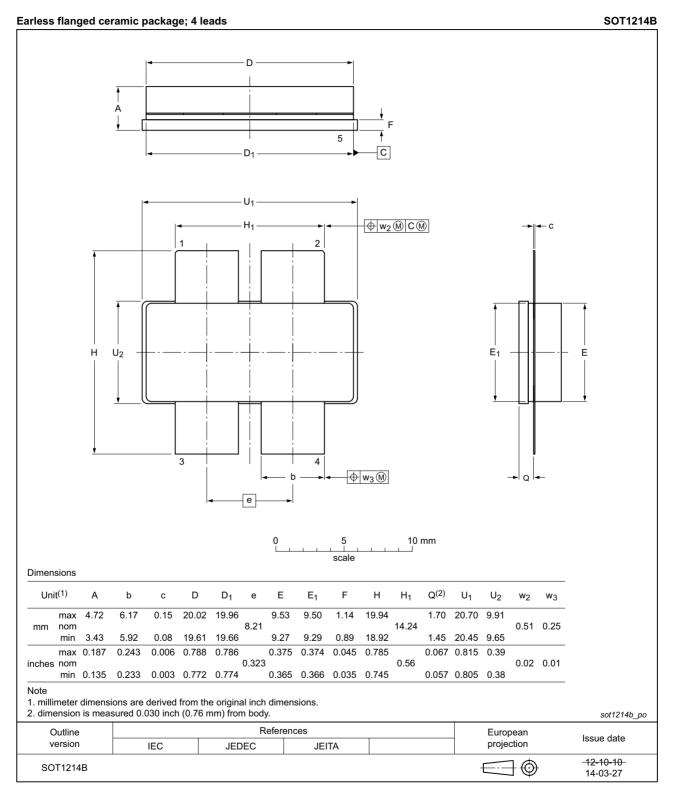


Fig 18. Package outline SOT1214B

ART2K0FE_2K0FES_2K0FEG

Product data sheet

ART700FH(S)(G) Power LDMOS transistor

SOT1214C

Earless flanged LDMOST ceramic package; 4 leads

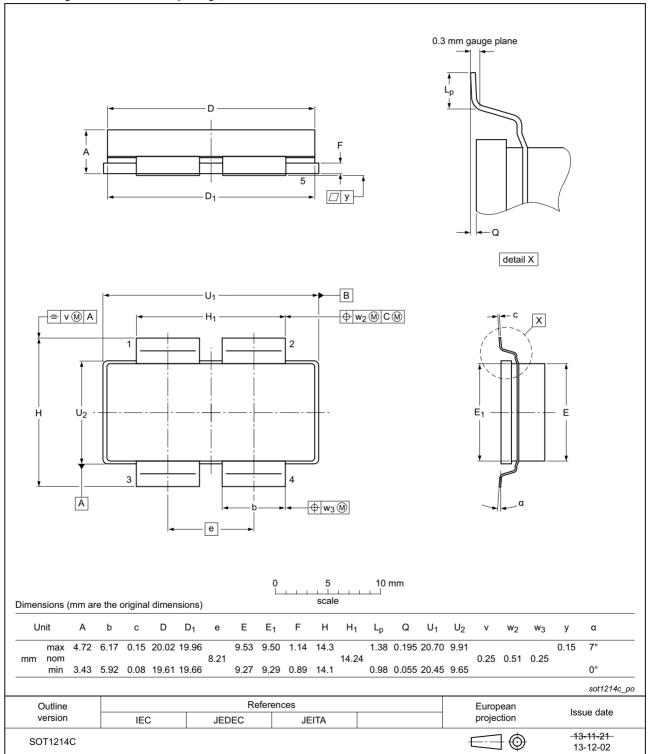


Fig 19. Package outline SOT1214C

ART2K0FE_2K0FES_2K0FEG

Product data sheet

9. Handling information

CAUTION



This device is sensitive to ElectroStatic Discharge (ESD). Observe precautions for handling electrostatic sensitive devices.

Such precautions are described in the ANSI/ESD S20.20, IEC/ST 61340-5, JESD625-A or equivalent standards.

Table 11.ESD sensitivity

| ESD model | Class |
|--|---------|
| Charged Device Model (CDM); According to ANSI/ESDA/JEDEC standard JS-002 | C2A [1] |
| Human Body Model (HBM); According to ANSI/ESDA/JEDEC standard JS-001 | 2 [2] |

[1] CDM classificationC2A is granted to any part that passes after exposure to an ESD pulse of 500 V.

[2] HBM classification 2 is granted to any part that passes after exposure to an ESD pulse of 2000 V.

10. Abbreviations

| Table 12. Abbre | viations |
|-----------------|--|
| Acronym | Description |
| CW | Continuous Wave |
| ESD | ElectroStatic Discharge |
| FM | Frequency Modulation |
| ISM | Industrial, Scientific and Medical |
| LDMOS | Laterally Diffused Metal-Oxide Semiconductor |
| MRI | Magnetic Resonance Imaging |
| MTF | Median Time to Failure |
| RoHS | Restriction of Hazardous Substances |
| SMD | Surface Mounted Device |
| UHF | Ultra High Frequency |
| VHF | Very High Frequency |
| VSWR | Voltage Standing Wave Ratio |

11. Revision history

Table 13.Revision history

| Document ID | Release date | Data sheet status | Change notice | Supersedes |
|----------------------------|--------------|-----------------------------|------------------|------------------------------|
| ART700FH_700FHS_700FHG v.3 | 20221118 | Product data sheet | - | ART700FH_700FHS_700FHG v.2 |
| Modifications: | • Table 3 on | page <u>3</u> : orderable p | art number of SO | T1214C changed to ART700FHGJ |
| ART700FH_700FHS_700FHG v.2 | 20220708 | Product data sheet | - | ART700FH v.1 |
| ART700FH v.1 | 20210924 | Product data sheet | - | - |

12. Legal information

12.1 Data sheet status

| Document status ^{[1][2]} | Product status ^[3] | Definition |
|-----------------------------------|-------------------------------|---|
| Objective [short] data sheet | Development | This document contains data from the objective specification for product development. |
| Preliminary [short] data sheet | Qualification | This document contains data from the preliminary specification. |
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[1] Please consult the most recently issued document before initiating or completing a design.

[2] The term 'short data sheet' is explained in section "Definitions".

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